

# Ultra-Fast Soft Recovery Diode Module

## Description

Ultra-FRD module devices are optimized to reduce losses and EMI/RFI in high frequency power conditioning electrical systems. These diode modules are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

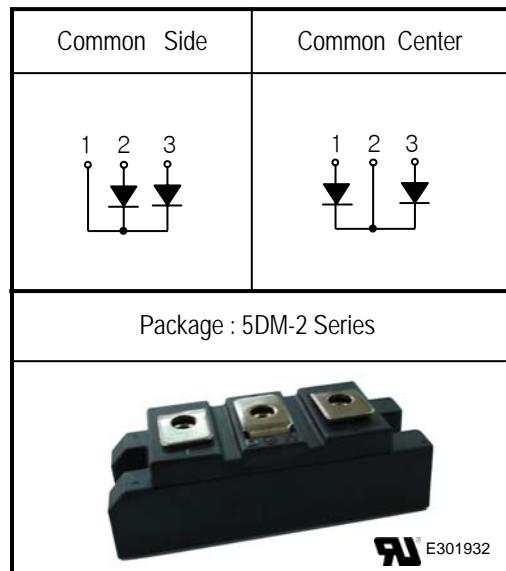
## Features

- ☞ Repetitive Reverse Voltage :  $V_{RRM} = 400V$
- ☞ Low Forward Voltage Drop :  $V_F(\text{typ.}) = 1.4V$
- ☞ Average Forward Current :  $I_F(\text{AV.}) = 150A @ T_c = 100^\circ\text{C}$
- ☞ Ultra-Fast Reverse Recovery Time :  $t_{rr}(\text{typ.}) = 150 \text{ ns}$
- ☞ Extensive Characterization of Recovery Parameters
- ☞ Reduced EMI and RFI
- ☞ Isolation Type Package

## Applications

Motor Drives, Free wheel use, High Power Converters, Welders, Various Switching and Telecommunication Power Supply.

## Equivalent Circuit and Package



E301932

Please see the package Out line information

## Ordering Information

Device Name	DB2F150N4S	DBC2F150N4S
Optional Information	Common Side	Common Center

## Absolute Maximum Ratings @ $T_j=25^\circ\text{C}$ (Per Leg)

Symbol	Parameter	Conditions	Ratings	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		400	V
$V_{RD(DC)}$	Reverse DC Voltage		320	V
$I_{F(\text{AV.})}$	Average Forward Current @ $T_c = 25^\circ\text{C}$ @ $T_c = 100^\circ\text{C}$	Resistive Load	300 150	A A
$I_{FSM}$	Surge(non-repetitive) Forward Current	One Half Cycle at 60Hz, Peak Value	2750	A
$I^2t$	$I^2t$ for Fusing	Value for One Cycle Current, $t_w = 8.3\text{ms}$ , $T_j = 25^\circ\text{C}$ Start	$37.5 \times 10^3$	$\text{A}^2\text{s}$
$T_j$	Junction Temperature		-40 ~ 150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature		-40 ~ 125	$^\circ\text{C}$
$V_{isol}$	Isolation Voltage	@ AC 1 minutes	2500	V
$P_d$	Maximum Power Dissipation		550	W
-	Mounting Torque		4.0	N.m
-	Terminal Torque		3.0	N.m
-	Weight	Typical Including Screws	180	g

## Thermal Characteristics

Symbol	Parameter	Conditions	Values			Unit
			Min.	Typ.	Max.	
$R_{th(j-c)}$	Thermal Resistance	Junction to Case	-	-	0.23	°C/W

## Electrical Characteristics @ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Conditions	Values			Unit
			Min.	Typ.	Max.	
$V_R$	Cathode Anode Breakdown Voltage	$I_R = 100\mu\text{A}$	400	-	-	V
$V_{FM}$	Maximum Forward Voltage	$I_{FM} = 150\text{A}, T_c = 25^\circ\text{C}$	-	1.4	1.6	V
		$I_{FM} = 150\text{A}, T_c = 100^\circ\text{C}$	-	1.2	1.4	V
$I_{RRM}$	Repetitive Peak Reverse Current	$T_c = 100^\circ\text{C}$ , $V_{RRM}$ applied	-	-	6.0	mA
$T_{rr}$	Reverse Recovery Time	$I_{FM} = 150\text{A}, V_R = 200\text{V}$	$T_c = 25^\circ\text{C}$	-	150	ns
		$\frac{dI}{dt} = -100\text{A/us}$	$T_c = 100^\circ\text{C}$	-	220	-

## Performance Curves

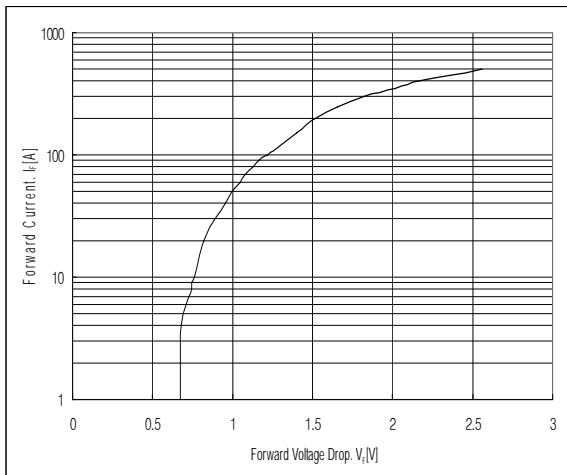


Fig. 1 : Typical Forward Voltage Drop  
vs. Instantaneous Forward Current

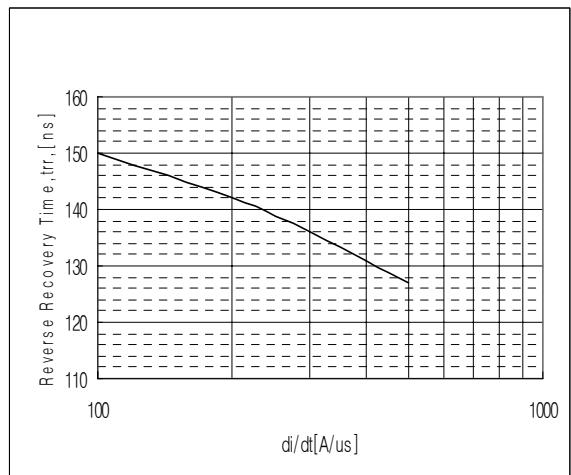


Fig. 2 : Typical Reverse Recovery Time  
vs. -di/dt

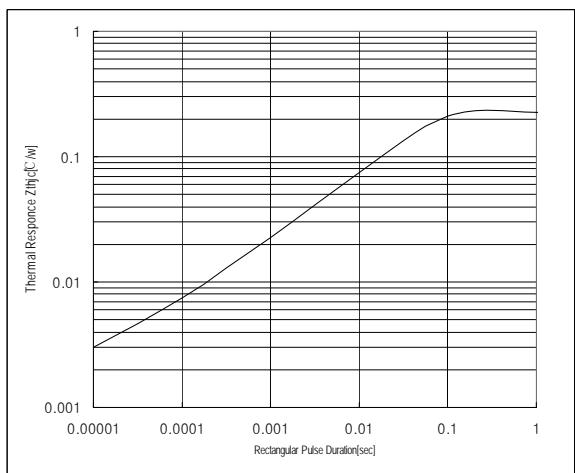


Fig. 3 : Transient Thermal Impedance( $Z_{thjc}$ )  
Characteristics

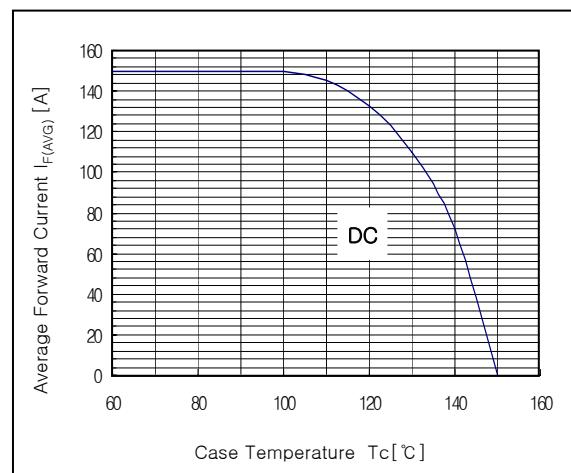


Fig. 4 : Forward Current Derating Curve

## Package Out Line Information

5DM-2 Series

